









Bill of Materials

Designator	Description	Value	Q
C1	Electrolytic capacitor 16v/50v	10µF	1
C2, C3	Ceramic or tantalum capacitor	100nF	2
IC2	4-bit D-Type Register with 3 state outputs	74LS173	1
IC4	4-Bits 2-Line to 1 Line data selector	74LS157	1
P1	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 16	δŗ 16p	1
P2	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 32	2ŗ 32p	1
Р3	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 8p	9p	1
P4	Socket Header, THT, pitch 2.54mm, Dual Row, Vertical,	. 24p	1
RN1	Resistor array 8 elements,9 pins	1K	1
SW1	DIP switch 4 positions	4 pos	1
SW2	Mini slide switch 2 pos, 3 pins		1



Assembly List

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C1	Electrolytic capacitor 16v/50v	10µF
C2	Ceramic or tantalum capacitor	100nF
C3	Ceramic or tantalum capacitor	100nF
IC2	4-bit D-Type Register with 3 state outputs	74LS173
IC4	4-Bits 2-Line to 1 Line data selector	74LS157
P1	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 16p	16p
P2	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 32p	32p
Р3	Pin Header, THT, pitch 2.54mm, Dual Row, Vertical, 8p	8p
P4	Socket Header, THT, pitch 2.54mm, Dual Row, Vertical, 24r	24p
RN1	Resistor array 8 elements,9 pins	1K
SW1	DIP switch 4 positions	4 pos
SW2	Mini slide switch 2 pos, 3 pins	